# VS-HFA12PA120C-N3

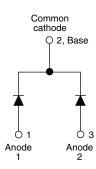
Vishay Semiconductors

# HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 6 A



www.vishay.com





PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	2 x 6 A							
V <sub>R</sub>	1200 V							
V <sub>F</sub> at I <sub>F</sub>	2.4 V							
t <sub>rr</sub> typ.	26 ns							
T <sub>J</sub> max.	150 °C							
Package	TO-247AC 3L							
Circuit configuration	Common cathode							

### FEATURES

- Ultrafast and ultrasoft recovery
- Very low I<sub>RRM</sub> and Q<sub>rr</sub>
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

### DESCRIPTION

VS-HFA12PA120C... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. The VS-HFA12PA120C... has basic ratings of 1200 V and 6 A per leg continuous current. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>BBM</sub>) and does not exhibit any tendency to "snap-off" during the t<sub>b</sub> portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA12PA120C... is ideally suited for applications in power supplies and power conversion systems (such as inverters, converters, UPS systems, and power factor correction circuits), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Cathode to anode voltage	V <sub>R</sub>		1200	V				
Maximum continuous forward currentper leg		T <sub>C</sub> = 100 °C	6					
per device	I <sub>F</sub>	$1_{\rm C} = 100$ C	12	А				
Single pulse forward current	I <sub>FSM</sub>	t <sub>p</sub> = 10 ms	80	A				
Maximum repetitive forward current	I <sub>FRM</sub>		24					
Maximum neuror discinction	Р	T <sub>C</sub> = 25 °C	62.5	W				
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 100 °C	25	vv				
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C				

Revision: 11-Oct-2019

1

Document Number: 94597

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



RoHS COMPLIANT HALOGEN FREE

VS-HFA12PA120C-N3



# Vishay Semiconductors

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	1200	-	-				
Maximum forward voltage		I <sub>F</sub> = 6 A	-	2.7	3.0	V			
	V <sub>FM</sub>	I <sub>F</sub> = 12 A	-	3.5	3.9				
		I <sub>F</sub> = 6 A, T <sub>J</sub> = 125 °C	-	2.4	2.8				
Maximum reverse		$V_{R} = V_{R}$ rated	-	0.26	5.0				
leakage current	I <sub>RM</sub>	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$ - 110		110	500	μA			
Junction capacitance	CT	V <sub>R</sub> = 200 V	-	9.0	14	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

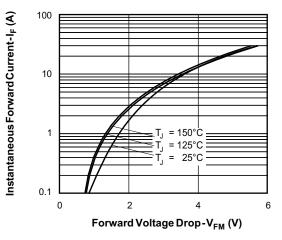
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	A/ $\mu$ s, V <sub>R</sub> = 30 V	-	26	-			
	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	53	80	ns		
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C	I <sub>F</sub> = 6 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	87	130			
Peak recovery current	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	4.4	8.0	A nC		
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	5.0	9.0			
	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	116	320			
Reverse recovery charge	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = 200 V	-	233	585			
Peak rate of fall of recovery	dl <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	180	-	A∕µs		
current during t <sub>b</sub>	dl <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	100	-	γγµs		

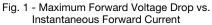
THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C				
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	2.0					
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.50	-					
Weight			-	2.0	-	g				
weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC 3L		HFA12	PA120C					



# VS-HFA12PA120C-N3

## **Vishay Semiconductors**





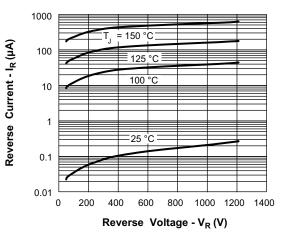


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

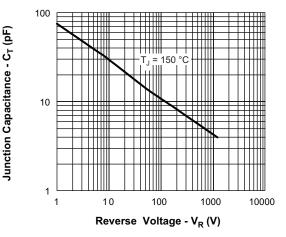


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

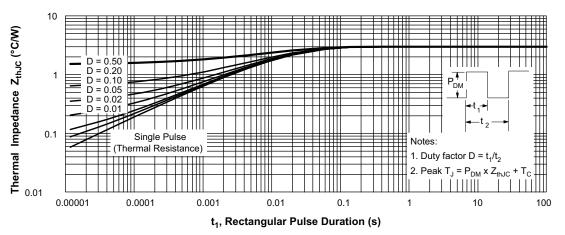


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

 Revision: 11-Oct-2019
 3
 Document Number: 94597

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

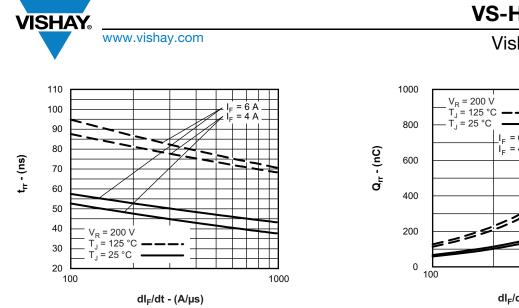


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

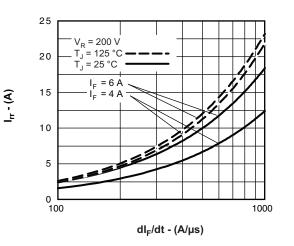


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt

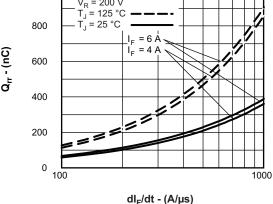


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

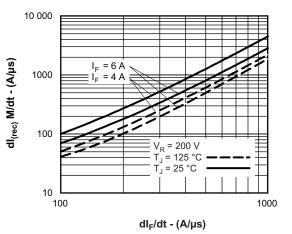
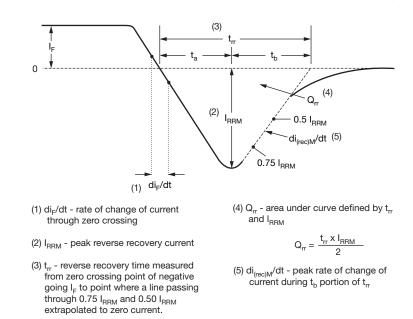


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$ 



#### Fig. 9 - Reverse Recovery Waveform and Definitions

Revision: 11-Oct-2019	4	Document Number: 94597
For technical questions within your region	: DiodesAmericas@vishay.com, DiodesAsia@vishay.com	n, <u>DiodesEurope@vishay.com</u>
	E WITHOUT NOTICE. THE PRODUCTS DESCRIBED HE	
ARE SUBJECT TO SPEC	CIFIC DISCLAIMERS, SET FORTH AT <a href="https://www.vishay.com/c">www.vishay.com/c</a>	<u>doc?91000</u>



## **Vishay Semiconductors**



# Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

Device code	VS-	HF	Α	12	PA	120	С	-N3
		2	3	4	5	6	7	8
	1 -			niconduc	ctors pro	oduct		
	2 -		KFRED <sup>®</sup>	-				
	4 -			ng (12 =	= 12 A)			
	5 -	PA	= TO-24	47AC, 3	pins			
	6 -	Vol	age rati	ng: (120	) = 1200	) V)		
	7 -			iguratior				
	8			ntal digit		oomolic	nt and	totolly
		-193	– nalog	gen-free	, KUHS-	complia	ini, and	locally

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	PACKAGING DESCRIPTION						
VS-HFA12PA120C-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96138						
Part marking information	www.vishay.com/doc?95007						



**Vishay Semiconductors** 

TO-247AC 3L

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4							

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension Q

Revision: 20-Jun-17

1



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.